

## Precision Monolithic Quad SPST CMOS Analog Switches

### DESCRIPTION

The DG417B, DG418B, DG419B monolithic CMOS analog switches were designed to provide high performance switching of analog signals. Combining low power, low leakages, high speed, low on-resistance and small physical size, the DG417B series is ideally suited for portable and battery powered industrial and military applications requiring high performance and efficient use of board space.

To achieve high-voltage ratings and superior switching performance, the DG417B series is built on Vishay Siliconix's high voltage silicon gate (HVSG) process. Break-before-make is guaranteed for the DG419B, which is an SPDT configuration. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG417B and DG418B respond to opposite control logic levels as shown in the Truth Table.

### FEATURES

- $\pm 15$  V analog signal range
- On-resistance -  $R_{DS(on)}$ :  $15\ \Omega$
- Fast switching action -  $t_{ON}$ : 110 ns
- TTL and CMOS compatible
- MSOP-8 and SOIC-8 package
- Compliant to RoHS directive 2002/95/EC



**RoHS\***  
COMPLIANT

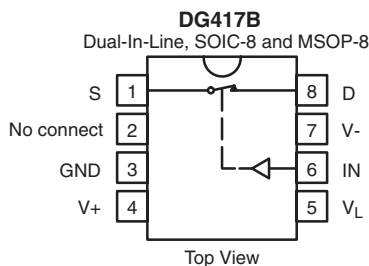
### BENEFITS

- Widest dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing
- Reduced board space
- Improved reliability

### APPLICATIONS

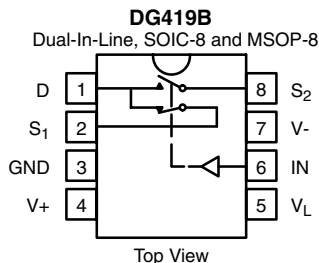
- Precision test equipment
- Precision instrumentation
- Battery powered systems
- Sample-and-hold circuits
- Military radios
- Guidance and control systems
- Hard disk drivers

### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE |        |        |
|-------------|--------|--------|
| Logic       | DG417B | DG418B |
| 0           | ON     | OFF    |
| 1           | OFF    | ON     |

Logic "0"  $\leq 0.8$  V  
Logic "1"  $\geq 2.4$  V



| TRUTH TABLE - DG419B |                 |                 |
|----------------------|-----------------|-----------------|
| Logic                | SW <sub>1</sub> | SW <sub>2</sub> |
| 0                    | ON              | OFF             |
| 1                    | OFF             | ON              |

Logic "0"  $\leq 0.8$  V  
Logic "1"  $\geq 2.4$  V

\* Pb containing terminations are not RoHS compliant, exemptions may apply

| ORDERING INFORMATION |                       |                                                          |
|----------------------|-----------------------|----------------------------------------------------------|
| Temp Range           | Package               | Part Number                                              |
| DG417B, DG418B       |                       |                                                          |
| - 40 °C to 85 °C     | 8-Pin Plastic MiniDIP | DG417BDJ<br>DG417BDJ-E3                                  |
|                      |                       | DG418BDJ<br>DG418BDJ-E3                                  |
|                      | 8-Pin Narrow SOIC     | DG417BDY<br>DG417BDY-E3<br>DG417BDY-T1<br>DG417BDY-T1-E3 |
|                      |                       | DG418BDY<br>DG418BDY-E3<br>DG418BDY-T1<br>DG418BDY-T1-E3 |
|                      | 8-Pin MSOP            | DG417BDQ-T1-E3                                           |
|                      |                       | DG418BDQ-T1-E3                                           |
| DG419B               |                       |                                                          |
| - 40 °C to 85 °C     | 8-Pin Plastic MiniDIP | DG419BDJ<br>DG419BDJ-E3                                  |
|                      | 8-Pin Narrow SOIC     | DG419BDY<br>DG419BDY-E3<br>DG419BDY-T1<br>DG419BDY-T1-E3 |
|                      | 8-Pin MSOP            | DG419BDQ-T1-E3                                           |

| ABSOLUTE MAXIMUM RATINGS                                      |                                    |                                                            |      |
|---------------------------------------------------------------|------------------------------------|------------------------------------------------------------|------|
| Parameter                                                     |                                    | Limit                                                      | Unit |
| V-                                                            |                                    | - 20                                                       | V    |
| V+                                                            |                                    | 20                                                         |      |
| GND                                                           |                                    | 25                                                         |      |
| V <sub>L</sub>                                                |                                    | (GND - 0.3) to (V+) + 0.3                                  |      |
| Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub> |                                    | (V-) - 2 V to (V+) + 2<br>or 30 mA, whichever occurs first |      |
| Current, (Any Terminal) Continuous                            |                                    | 30                                                         | mA   |
| Current (S or D) Pulsed at 1 ms, 10 % Duty Cycle              |                                    | 100                                                        |      |
| Storage Temperature                                           |                                    | - 65 to 150                                                | °C   |
| Power Dissipation (Package) <sup>b</sup>                      | 8-Pin Plastic MiniDIP <sup>c</sup> | 400                                                        | mW   |
|                                                               | 8-Pin Narrow SOIC <sup>c</sup>     | 400                                                        |      |
|                                                               | 8-Pin MSOP <sup>d</sup>            | 400                                                        |      |
|                                                               | 8-Pin CerDIP <sup>e</sup>          | 600                                                        |      |

Notes:

a. Signals on S<sub>X</sub>, D<sub>X</sub>, or I<sub>NX</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 5.3 mW/°C above 75 °C.

d. Derate 4 mW/°C above 70 °C.

e. Derate 8 mW/°C above 75 °C.

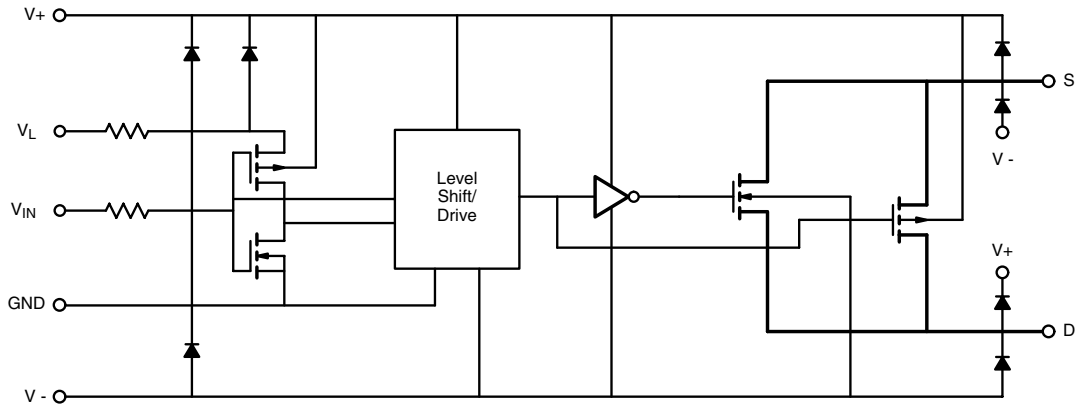
**SCHEMATIC DIAGRAM** Typical Channel


Figure 1.

| SPECIFICATIONS <sup>a</sup>               |                     |                                                                                                                                                                      |  |                     |                   |                               |                   |                              |                   |      |
|-------------------------------------------|---------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|---------------------|-------------------|-------------------------------|-------------------|------------------------------|-------------------|------|
| Parameter                                 | Symbol              | Test Conditions<br>Unless Otherwise Specified<br>V <sub>+</sub> = 15 V, V <sub>-</sub> = - 15 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup> |  | Temp. <sup>b</sup>  | Typ. <sup>c</sup> | A Suffix<br>- 55 °C to 125 °C |                   | D Suffix<br>- 40 °C to 85 °C |                   | Unit |
|                                           |                     |                                                                                                                                                                      |  |                     |                   | Min. <sup>d</sup>             | Max. <sup>d</sup> | Min. <sup>d</sup>            | Max. <sup>d</sup> |      |
| Analog Switch                             |                     |                                                                                                                                                                      |  |                     |                   |                               |                   |                              |                   |      |
| Analog Signal Range <sup>e</sup>          | V <sub>ANALOG</sub> |                                                                                                                                                                      |  | Full                |                   | - 15                          | 15                | - 15                         | 15                | V    |
| Drain-Source On-Resistance                | R <sub>DS(on)</sub> | I <sub>S</sub> = - 10 mA, V <sub>D</sub> = ± 12.5 V<br>V <sub>+</sub> = 13.5 V, V <sub>-</sub> = - 13.5 V                                                            |  | Room Full           | 15                |                               | 25<br>34          |                              | 25<br>29          | Ω    |
| Switch Off Leakage Current                | I <sub>S(off)</sub> | V <sub>+</sub> = 16.5, V <sub>-</sub> = - 16.5 V<br>V <sub>D</sub> = ± 15.5 V, V <sub>S</sub> = ± 15.5 V                                                             |  | Room Full           | - 0.1             | - 0.25<br>- 20                | 0.25<br>20        | - 0.25<br>- 5                | 0.25<br>5         | nA   |
|                                           | DG417B<br>Room Full |                                                                                                                                                                      |  | - 0.1               | - 0.25<br>- 20    | 0.25<br>20                    | - 0.25<br>- 5     | 0.25<br>5                    |                   |      |
|                                           | DG419B<br>Room Full |                                                                                                                                                                      |  | - 0.1               | - 0.75<br>- 60    | 0.75<br>60                    | - 0.75<br>- 12    | 0.75<br>12                   |                   |      |
| Channel On Leakage Current                | I <sub>D(on)</sub>  | V <sub>+</sub> = 16.5 V, V <sub>-</sub> = - 16.5 V<br>V <sub>S</sub> = V <sub>D</sub> = ± 15.5 V                                                                     |  | DG417B<br>Room Full | - 0.4             | - 0.4<br>- 40                 | 0.4<br>40         | - 0.4<br>- 10                | 0.4<br>10         |      |
|                                           |                     |                                                                                                                                                                      |  | DG419B<br>Room Full | - 0.4             | - 0.75<br>- 60                | 0.75<br>60        | - 0.75<br>- 12               | 0.75<br>12        |      |
| Digital Control                           |                     |                                                                                                                                                                      |  |                     |                   |                               |                   |                              |                   |      |
| Input Current, V <sub>IN</sub> Low        | I <sub>IL</sub>     |                                                                                                                                                                      |  | Full                |                   | - 0.5                         | 0.5               | - 0.5                        | 0.5               | μA   |
| Input Current, V <sub>IN</sub> High       | I <sub>IH</sub>     |                                                                                                                                                                      |  | Full                |                   | - 0.5                         | 0.5               | - 0.5                        | 0.5               |      |
| Dynamic Characteristics                   |                     |                                                                                                                                                                      |  |                     |                   |                               |                   |                              |                   |      |
| Turn-On Time                              | t <sub>ON</sub>     | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = ± 10 V, See Switching Time Test Circuit                                                           |  | DG417B<br>Room Full | 62                |                               | 89<br>106         |                              | 89<br>99          | ns   |
| Turn-Off Time                             | t <sub>OFF</sub>    |                                                                                                                                                                      |  | DG417B<br>Room Full | 53                |                               | 80<br>88          |                              | 80<br>86          |      |
| Transition Time                           | t <sub>TRANS</sub>  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S1</sub> = ± 10 V, V <sub>S2</sub> = ± 10 V                                                                 |  | DG419B<br>Room Full | 60                |                               | 87<br>96          |                              | 87<br>93          |      |
| Break-Before-Make Time Delay              | t <sub>D</sub>      | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S1</sub> = V <sub>S2</sub> = ± 10 V                                                                         |  | DG419B<br>Room      | 16                | 3                             |                   | 3                            |                   |      |
| Charge Injection                          | Q                   | C <sub>L</sub> = 10 nF<br>V <sub>gen</sub> = 0 V, R <sub>gen</sub> = 0 Ω                                                                                             |  | Room                | 38                |                               |                   |                              |                   | pC   |
| Off Isolation <sup>e</sup>                | OIRR                | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF,<br>f = 1 MHz                                                                                                           |  | Room                | - 82              |                               |                   |                              |                   | dB   |
| Channel-to-Channel Crosstalk <sup>e</sup> | X <sub>TALK</sub>   |                                                                                                                                                                      |  | DG419B<br>Room      | - 88              |                               |                   |                              |                   |      |

| SPECIFICATIONS <sup>a</sup>         |                     |                                                                                                                                                                      |                   |                    |                   |                               |                   |                              |    |      |
|-------------------------------------|---------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|--------------------|-------------------|-------------------------------|-------------------|------------------------------|----|------|
| Parameter                           | Symbol              | Test Conditions<br>Unless Otherwise Specified<br>V <sub>+</sub> = 15 V, V <sub>-</sub> = - 15 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup> |                   | Temp. <sup>b</sup> | Typ. <sup>c</sup> | A Suffix<br>- 55 °C to 125 °C |                   | D Suffix<br>- 40 °C to 85 °C |    | Unit |
|                                     |                     | Min. <sup>d</sup>                                                                                                                                                    | Max. <sup>d</sup> |                    |                   | Min. <sup>d</sup>             | Max. <sup>d</sup> |                              |    |      |
| Dynamic Characteristics             |                     |                                                                                                                                                                      |                   |                    |                   |                               |                   |                              |    |      |
| Source Off Capacitance <sup>e</sup> | C <sub>S(off)</sub> | f = 1 MHz, V <sub>S</sub> = 0 V                                                                                                                                      | DG417B<br>DG418B  | Room               | 12                |                               |                   |                              |    | pF   |
| Drain Off Capacitance <sup>e</sup>  | C <sub>D(off)</sub> |                                                                                                                                                                      | DG417B<br>DG418B  | Room               | 12                |                               |                   |                              |    |      |
| Channel On Capacitance <sup>e</sup> | C <sub>D(on)</sub>  | f = 1 MHz, V <sub>S</sub> = 0 V                                                                                                                                      | DG417B<br>DG418B  | Room               | 50                |                               |                   |                              |    |      |
|                                     |                     |                                                                                                                                                                      | DG419B            | Room               | 57                |                               |                   |                              |    |      |
| Power Supplies                      |                     |                                                                                                                                                                      |                   |                    |                   |                               |                   |                              |    |      |
| Positive Supply Current             | I <sub>+</sub>      | V <sub>+</sub> = 16.5 V, V <sub>-</sub> = - 16.5 V<br>V <sub>IN</sub> = 0 or 5 V                                                                                     | Room<br>Full      | 0.001              |                   | 1<br>5                        |                   | 1<br>5                       | μA |      |
| Negative Supply Current             | I <sub>-</sub>      |                                                                                                                                                                      | Room<br>Full      | - 0.001            | - 1<br>- 5        |                               | - 1<br>- 5        |                              |    |      |
| Logic Supply Current                | I <sub>L</sub>      |                                                                                                                                                                      | Room<br>Full      | 0.001              |                   | 1<br>5                        |                   | 1<br>5                       |    |      |
| Ground Current                      | I <sub>GND</sub>    |                                                                                                                                                                      | Room<br>Full      | - 0.001            | - 1<br>- 5        |                               | - 1<br>- 5        |                              |    |      |

| SPECIFICATIONS <sup>a</sup>      |                     |                                                                                                                                                                   |        |                    |                   |                               |                   |                              |                   |      |
|----------------------------------|---------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|--------------------|-------------------|-------------------------------|-------------------|------------------------------|-------------------|------|
| Parameter                        | Symbol              | Test Conditions<br>Unless Otherwise Specified<br>V <sub>+</sub> = 12 V, V <sub>-</sub> = 0 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup> |        | Temp. <sup>b</sup> | Typ. <sup>c</sup> | A Suffix<br>- 55 °C to 125 °C |                   | D Suffix<br>- 40 °C to 85 °C |                   | Unit |
|                                  |                     |                                                                                                                                                                   |        |                    |                   | Min. <sup>d</sup>             | Max. <sup>d</sup> | Min. <sup>d</sup>            | Max. <sup>d</sup> |      |
| Analog Switch                    |                     |                                                                                                                                                                   |        |                    |                   |                               |                   |                              |                   |      |
| Analog Signal Range <sup>e</sup> | V <sub>ANALOG</sub> |                                                                                                                                                                   |        | Full               |                   | 0                             | 12                | 0                            | 12                | V    |
| Drain-Source On-Resistance       | R <sub>DS(on)</sub> | I <sub>S</sub> = - 10 mA, V <sub>D</sub> = 3.8 V<br>V <sub>+</sub> = 10.8 V                                                                                       |        | Room Full          | 26                |                               | 35<br>52          |                              | 35<br>45          | Ω    |
| Dynamic Characteristics          |                     |                                                                                                                                                                   |        |                    |                   |                               |                   |                              |                   |      |
| Turn-On Time                     | t <sub>ON</sub>     | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = 8 V, See Switching Time Test Circuit                                                           |        | Room Full          | 100               |                               | 125<br>155        |                              | 125<br>143        | ns   |
| Turn-Off Time                    | t <sub>OFF</sub>    |                                                                                                                                                                   |        | Room Full          | 38                |                               | 66<br>73          |                              | 66<br>69          |      |
| Break-Before-Make Time Delay     | t <sub>D</sub>      | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF                                                                                                                    | DG419B | Room               | 62                | 25                            |                   | 25                           |                   |      |
| Transition Time                  | t <sub>TRANS</sub>  | R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF<br>V <sub>S1</sub> = 0 V, 8 V, V <sub>S2</sub> = 8 V, 0 V                                                          |        | Room Full          | 95                |                               | 119<br>153        |                              | 119<br>141        |      |
| Charge Injection                 | Q                   | C <sub>L</sub> = 10 nF, V <sub>gen</sub> = 0 V, R <sub>gen</sub> = 0 Ω                                                                                            |        | Room               | 18                |                               |                   |                              |                   | pC   |
| Power Supplies                   |                     |                                                                                                                                                                   |        |                    |                   |                               |                   |                              |                   |      |
| Positive Supply Current          | I <sub>+</sub>      | V <sub>+</sub> = 13.2 V, V <sub>L</sub> = 5.25 V<br>V <sub>IN</sub> = 0 or 5 V                                                                                    |        | Room Full          | 0.001             |                               | 1<br>5            |                              | 1<br>5            | μA   |
| Negative Supply Current          | I <sub>-</sub>      |                                                                                                                                                                   |        | Room               | - 0.001           | - 1<br>- 5                    |                   | - 1<br>- 5                   |                   |      |
| Logic Supply Current             | I <sub>L</sub>      |                                                                                                                                                                   |        | Room               | 0.001             |                               | 1<br>5            |                              | 1<br>5            |      |
| Ground Current                   | I <sub>GND</sub>    |                                                                                                                                                                   |        | Room               | - 0.001           | - 1<br>- 5                    |                   | - 1<br>- 5                   |                   |      |

Notes:

a. Refer to PROCESS OPTION FLOWCHART.

b. Room = 25 °C, full = as determined by the operating temperature suffix.

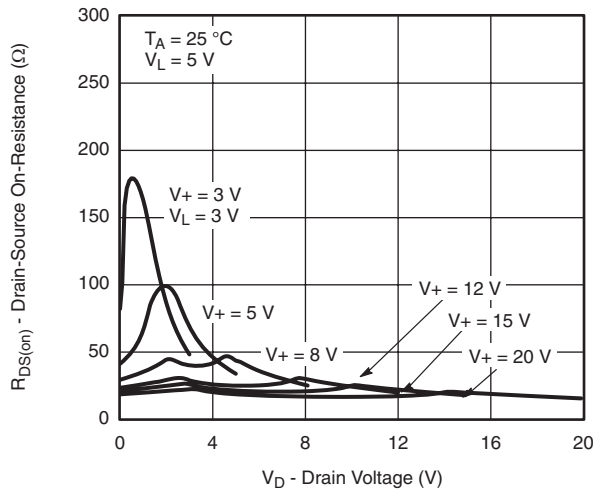
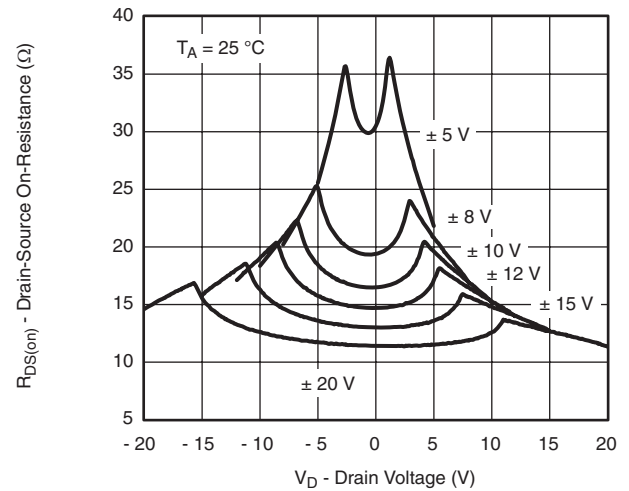
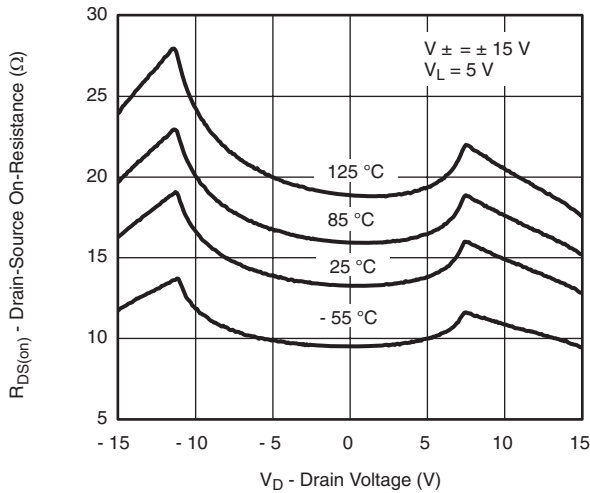
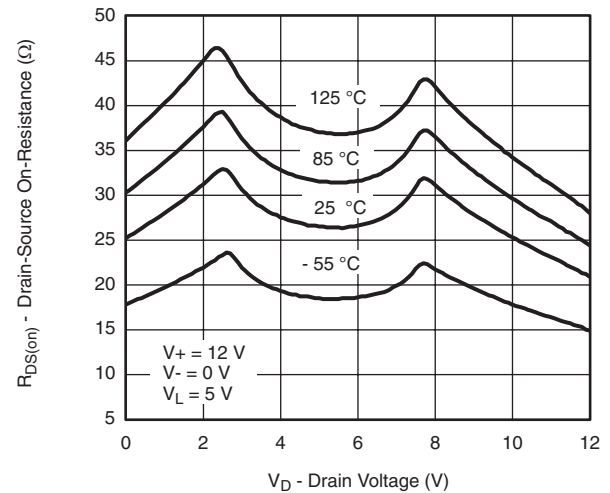
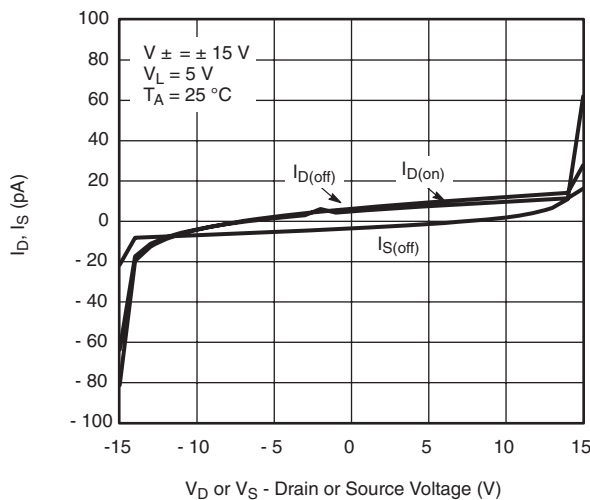
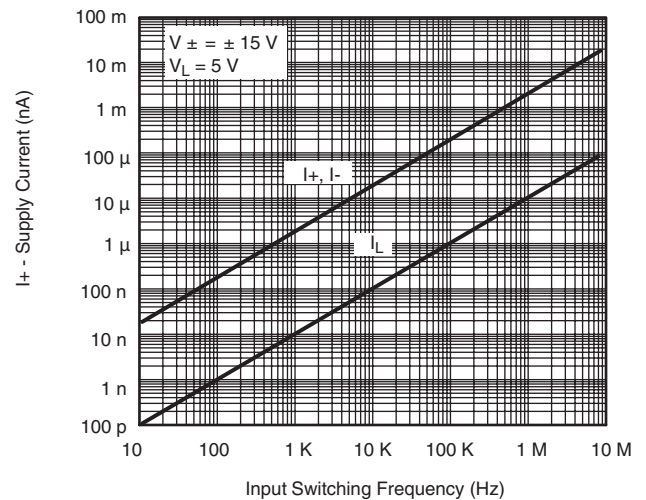
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.

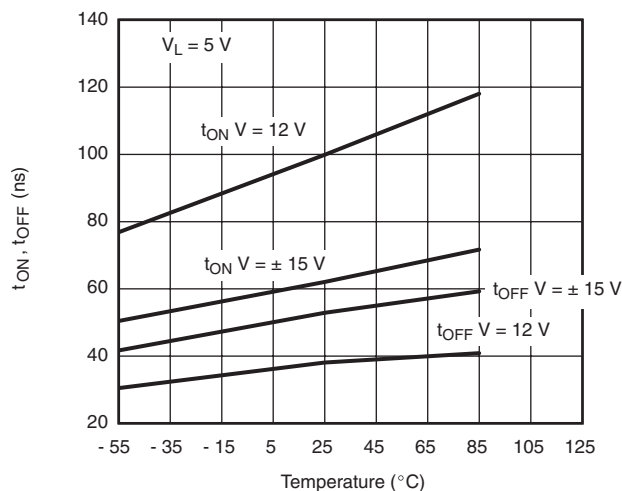
e. Guaranteed by design, not subject to production test.

f. V<sub>IN</sub> = input voltage to perform proper function.

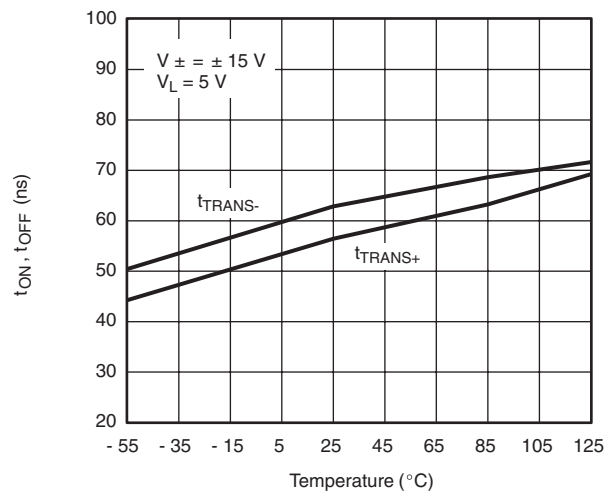
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS**  $T_A = 25^\circ\text{C}$ , unless otherwise noted

**On-Resistance vs.  $V_D$  and Unipolar Power Supply Voltage**

**On-Resistance vs.  $V_D$  and Dual Supply Voltage**

**On-Resistance vs.  $V_D$  and Temperature**

**On-Resistance vs.  $V_D$  and Temperature**

**Leakage vs. Analog Voltage**

**Supply Current vs. Input Switching Frequency**

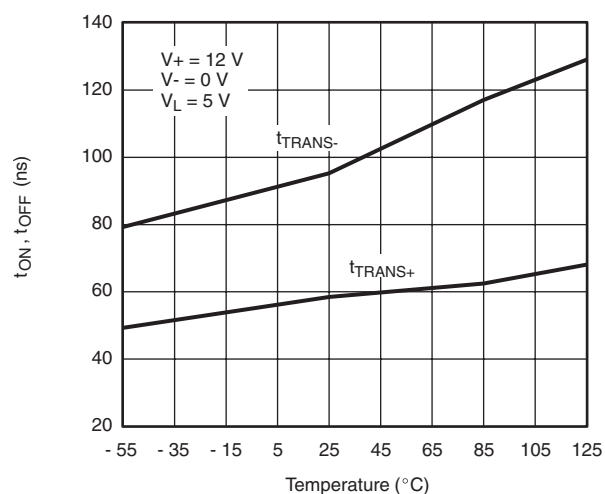
## TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$ , unless otherwise noted



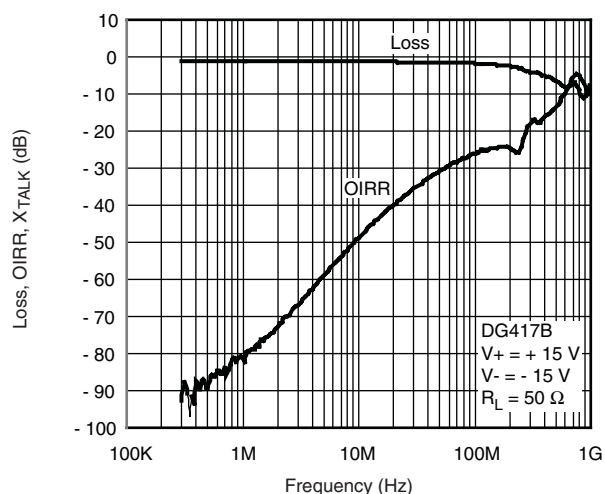
Switching Time vs. Temperature



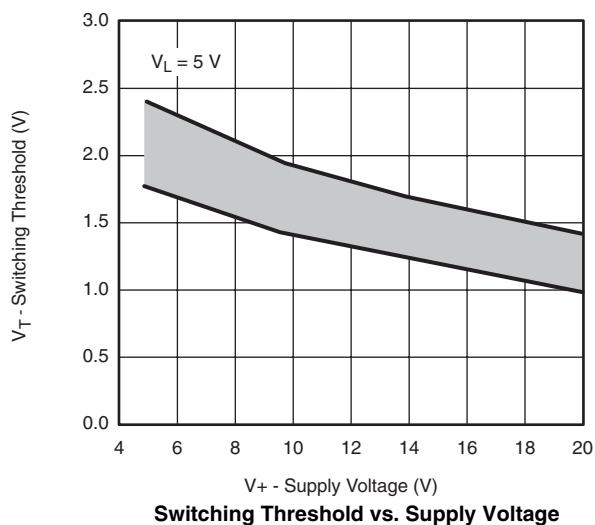
Transition Time vs. Temperature



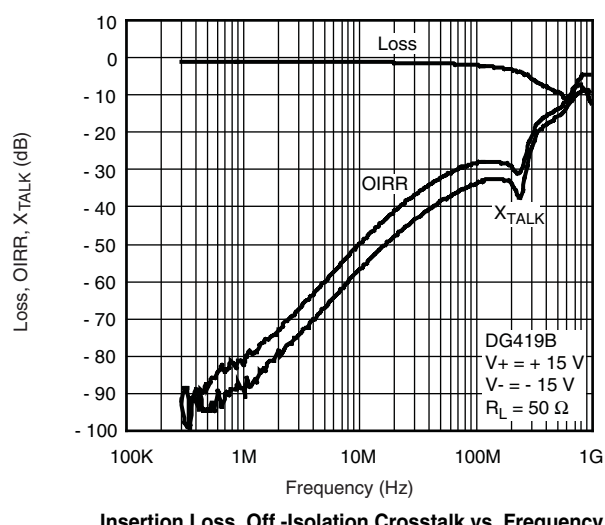
Transition Time vs. Temperature



Insertion Loss, Off-Isolation Crosstalk vs. Frequency

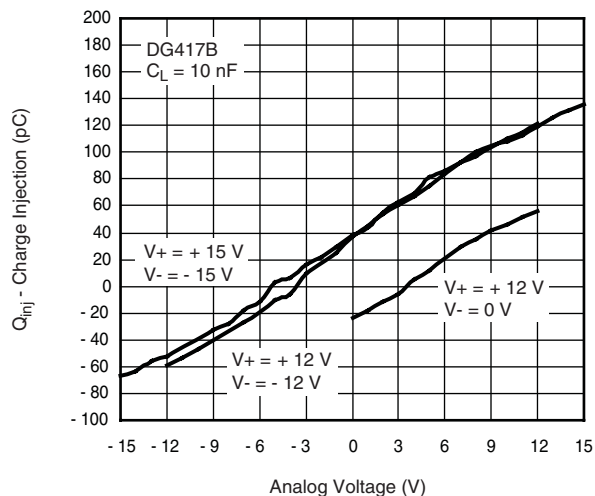


Switching Threshold vs. Supply Voltage

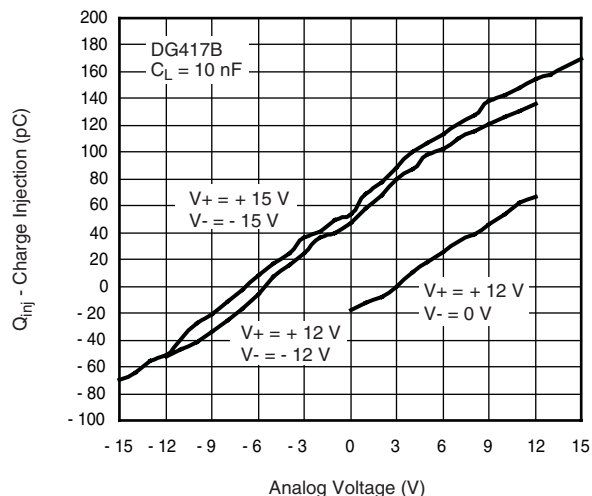


Insertion Loss, Off-Isolation Crosstalk vs. Frequency

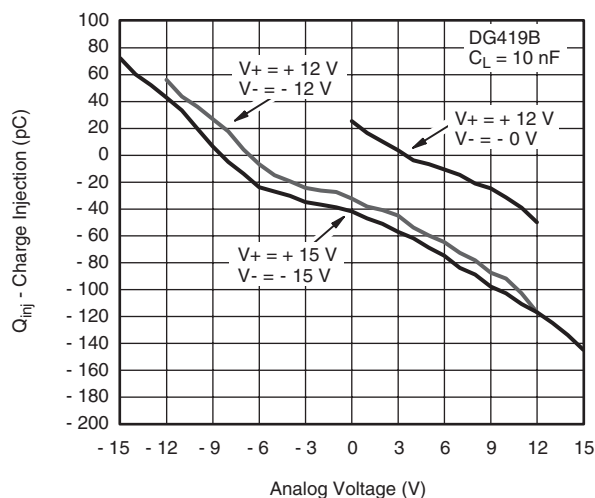
## TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$ , unless otherwise noted



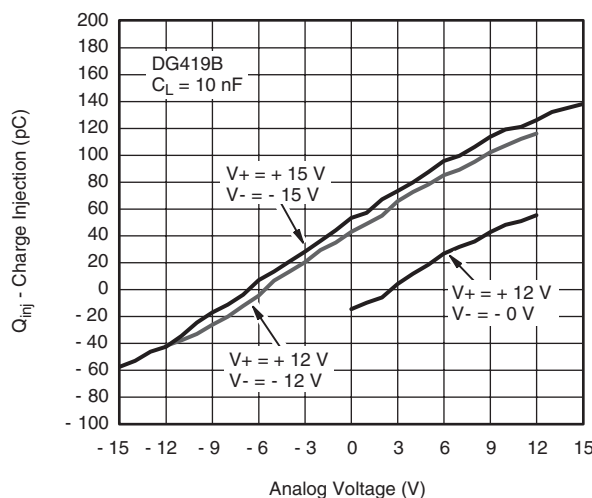
Charge Injection vs. Analog Voltage  
(Measured at drain pin)



Charge Injection vs. Analog Voltage  
(Measured at source pin)



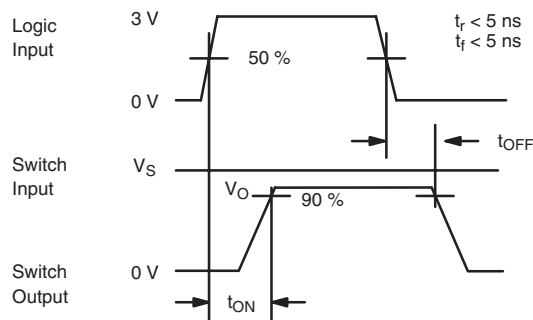
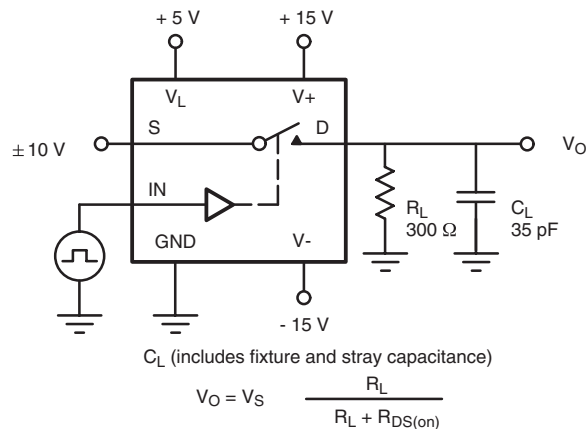
Charge Injection vs. Analog Voltage  
(Measured at drain pin)



Charge Injection vs. Analog Voltage  
(Measured at source pin)

## TEST CIRCUITS

$V_O$  is the steady state output with the switch on.



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

Figure 2. Switching Time (DG417B/418B)

## TEST CIRCUITS

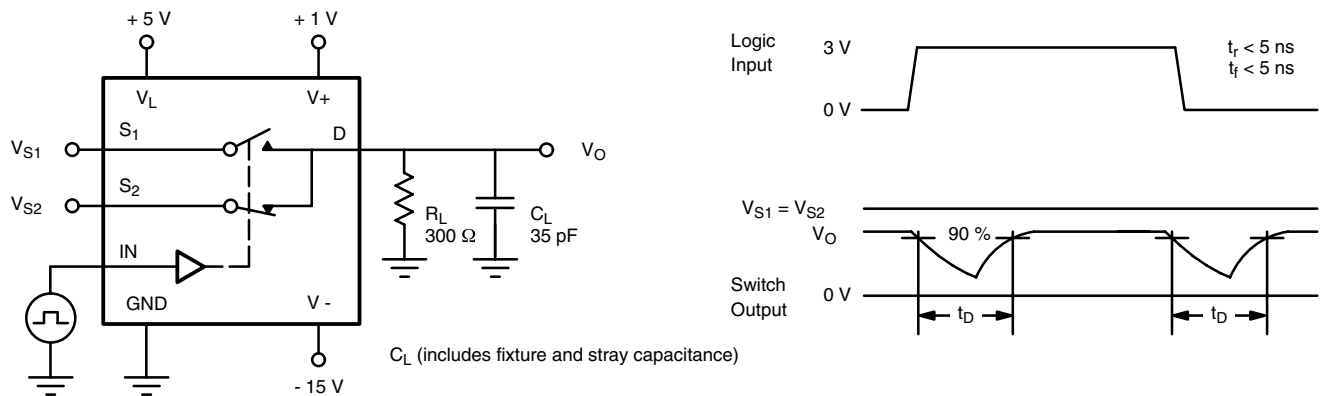


**Figure 3. Break-Before-Make (DG419B)**

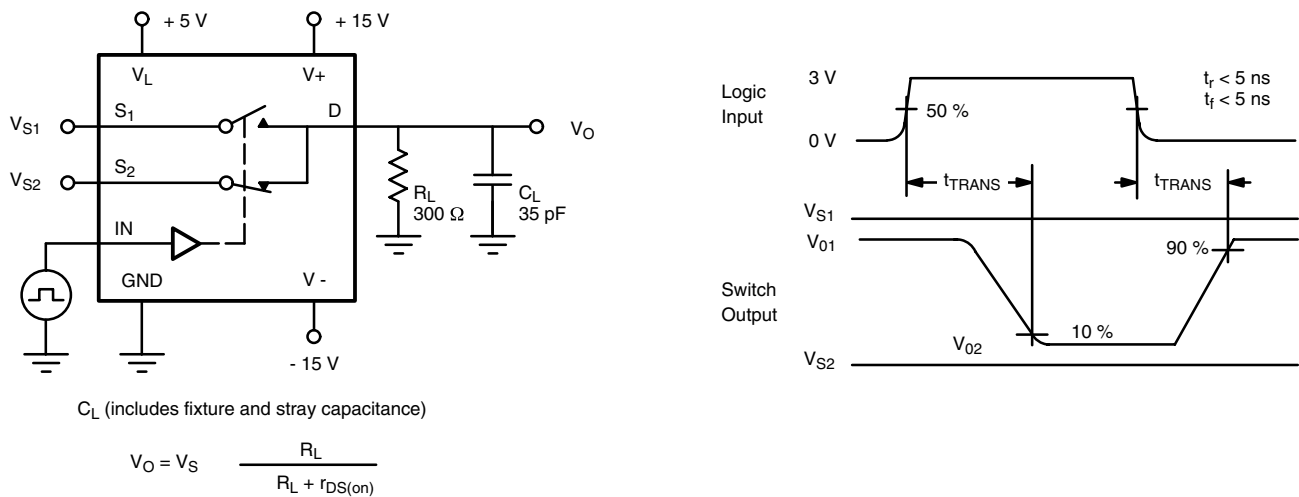
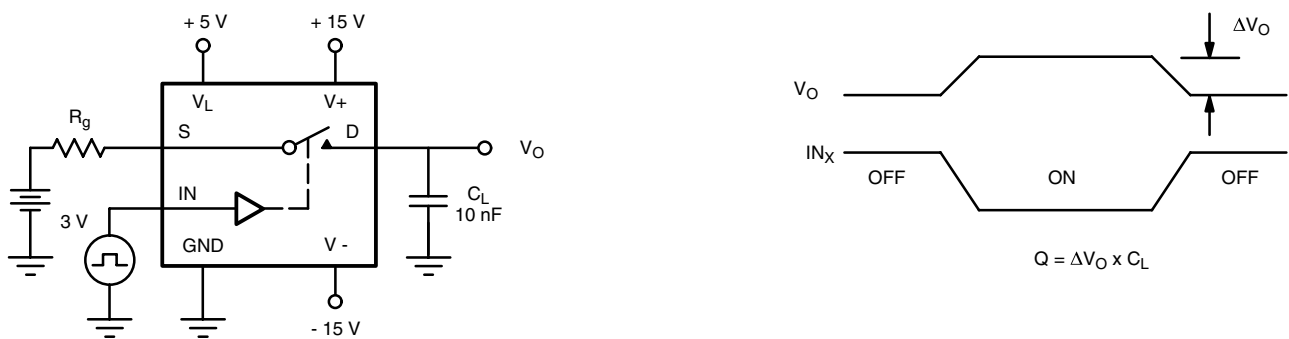
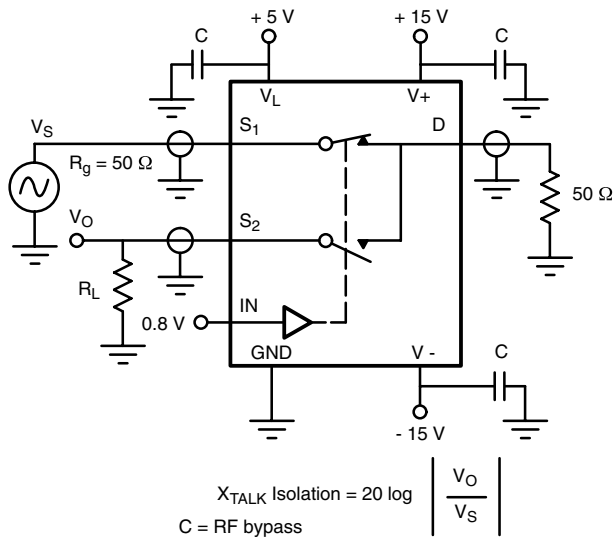
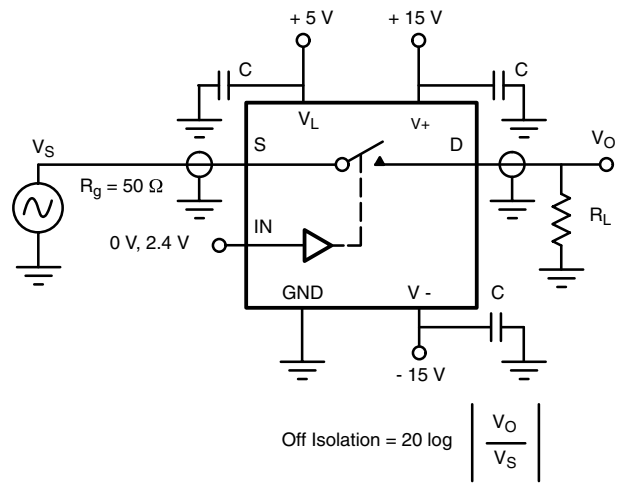
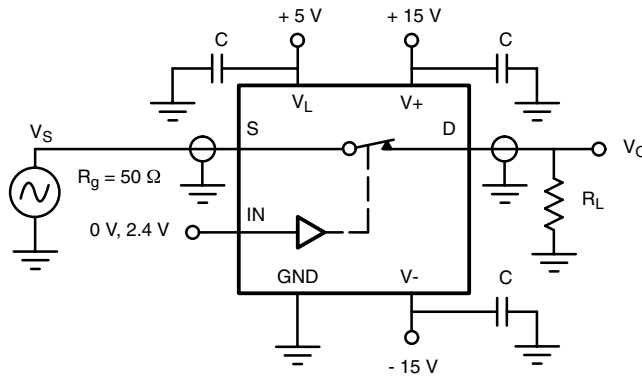
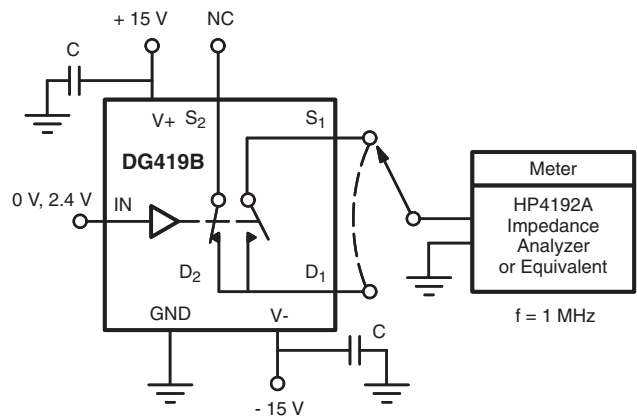
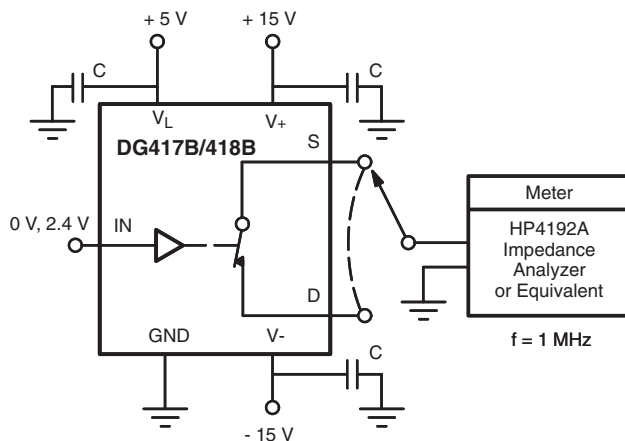


**Figure 4. Transition Time (DG419B)**



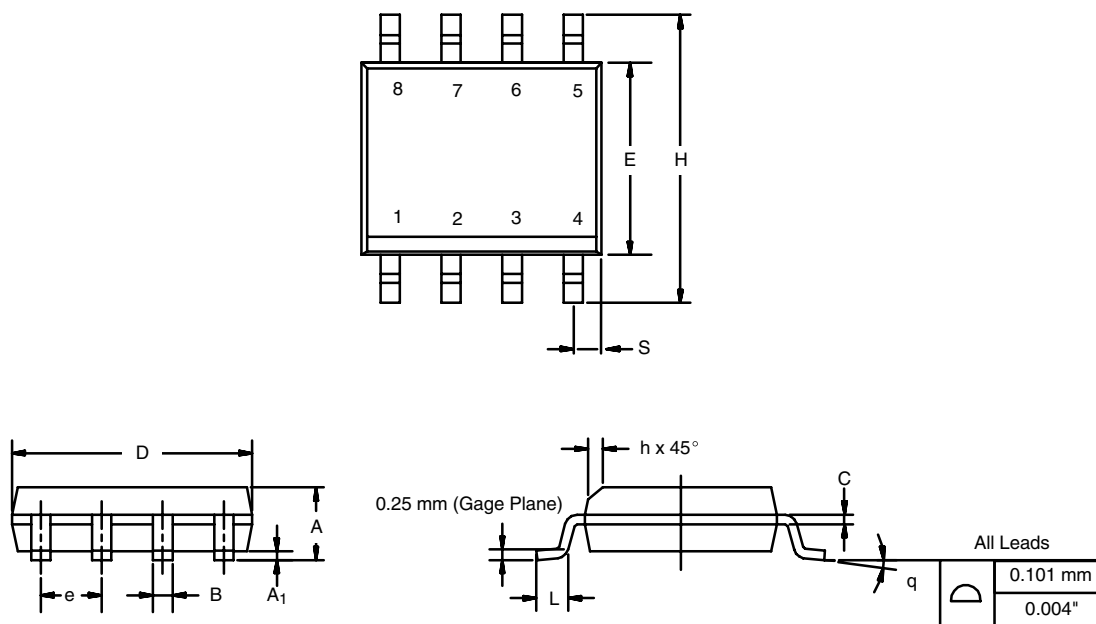
### Figure 5. Charge Injection

**TEST CIRCUITS**

**Figure 6. Crosstalk**

**Figure 7. Off isolation**

**Figure 8. Insertion Loss**

**Figure 9. Source/Drain Capacitances**

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?72107](http://www.vishay.com/ppg?72107).

## SOIC (NARROW): 8-LEAD

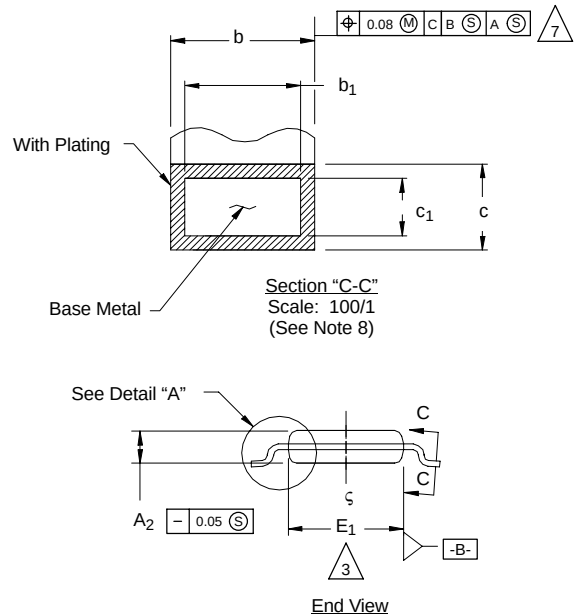
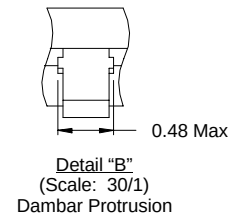
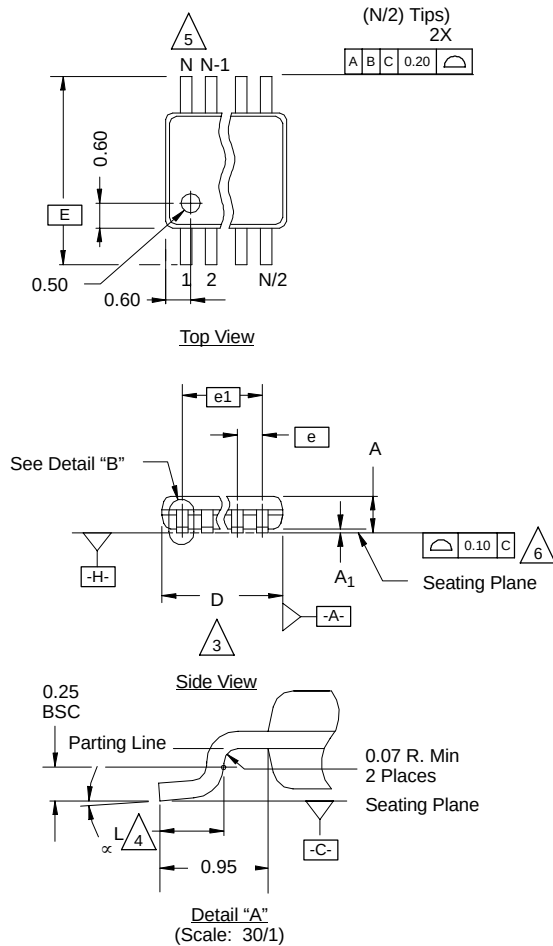
JEDEC Part Number: MS-012



| DIM                            | MILLIMETERS |      | INCHES    |       |
|--------------------------------|-------------|------|-----------|-------|
|                                | Min         | Max  | Min       | Max   |
| A                              | 1.35        | 1.75 | 0.053     | 0.069 |
| A <sub>1</sub>                 | 0.10        | 0.20 | 0.004     | 0.008 |
| B                              | 0.35        | 0.51 | 0.014     | 0.020 |
| C                              | 0.19        | 0.25 | 0.0075    | 0.010 |
| D                              | 4.80        | 5.00 | 0.189     | 0.196 |
| E                              | 3.80        | 4.00 | 0.150     | 0.157 |
| e                              | 1.27 BSC    |      | 0.050 BSC |       |
| H                              | 5.80        | 6.20 | 0.228     | 0.244 |
| h                              | 0.25        | 0.50 | 0.010     | 0.020 |
| L                              | 0.50        | 0.93 | 0.020     | 0.037 |
| q                              | 0°          | 8°   | 0°        | 8°    |
| S                              | 0.44        | 0.64 | 0.018     | 0.026 |
| ECN: C-06527-Rev. I, 11-Sep-06 |             |      |           |       |
| DWG: 5498                      |             |      |           |       |

### MSOP: 8-LEADS

JEDEC Part Number: MO-187, (Variation AA and BA)



#### NOTES:

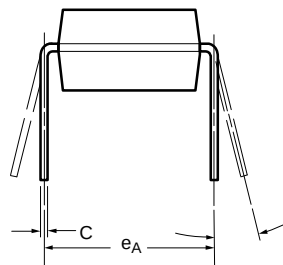
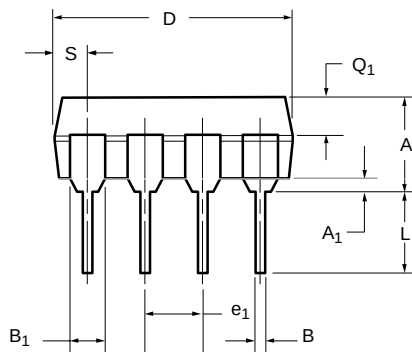
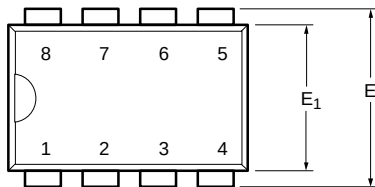
- Die thickness allowable is  $0.203 \pm 0.0127$ .
- Dimensioning and tolerances per ANSI.Y14.5M-1994.
- Dimensions "D" and "E<sub>1</sub>" do not include mold flash or protrusions, and are measured at Datum plane  $\square\text{H}\square$ , mold flash or protrusions shall not exceed 0.15 mm per side.
- Dimension is the length of terminal for soldering to a substrate.
- Terminal positions are shown for reference only.
- Formed leads shall be planar with respect to one another within 0.10 mm at seating plane.
- The lead width dimension does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08 mm total in excess of the lead width dimension at maximum material condition. Dambar cannot be located on the lower radius or the lead foot. Minimum space between protrusions and an adjacent lead to be 0.14 mm. See detail "B" and Section "C-C".
- Section "C-C" to be determined at 0.10 mm to 0.25 mm from the lead tip.
- Controlling dimension: millimeters.
- This part is compliant with JEDEC registration MO-187, variation AA and BA.
- Datums  $\square\text{A}\square$  and  $\square\text{B}\square$  to be determined Datum plane  $\square\text{H}\square$ .
- Exposed pad area in bottom side is the same as the leadframe pad size.

**N = 8L**

| Dim                            | MILLIMETERS |      |      | Note |
|--------------------------------|-------------|------|------|------|
|                                | Min         | Nom  | Max  |      |
| A                              | -           | -    | 1.10 |      |
| A <sub>1</sub>                 | 0.05        | 0.10 | 0.15 |      |
| A <sub>2</sub>                 | 0.75        | 0.85 | 0.95 |      |
| b                              | 0.25        | -    | 0.38 | 8    |
| b <sub>1</sub>                 | 0.25        | 0.30 | 0.33 | 8    |
| c                              | 0.13        | -    | 0.23 |      |
| c <sub>1</sub>                 | 0.13        | 0.15 | 0.18 |      |
| D                              | 3.00 BSC    |      |      | 3    |
| E                              | 4.90 BSC    |      |      |      |
| E <sub>1</sub>                 | 2.90        | 3.00 | 3.10 | 3    |
| e                              | 0.65 BSC    |      |      |      |
| e <sub>1</sub>                 | 1.95 BSC    |      |      |      |
| L                              | 0.40        | 0.55 | 0.70 | 4    |
| N                              | 8           |      |      | 5    |
| α                              | 0°          | 4°   | 6°   |      |
| ECN: T-02080—Rev. C, 15-Jul-02 |             |      |      |      |
| DWG: 5867                      |             |      |      |      |



### PDIP: 8-LEAD



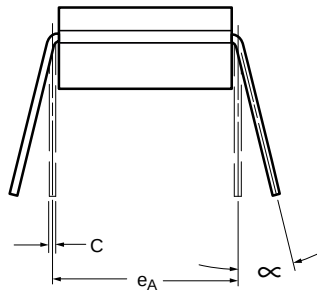
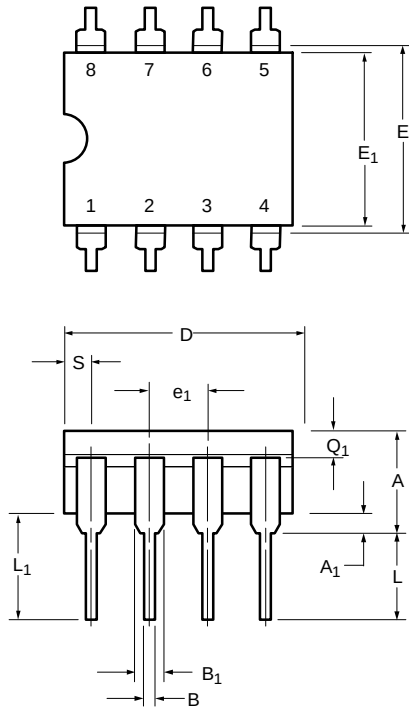
| Dim                  | MILLIMETERS |       | INCHES |       |
|----------------------|-------------|-------|--------|-------|
|                      | Min         | Max   | Min    | Max   |
| <b>A</b>             | 3.81        | 5.08  | 0.150  | 0.200 |
| <b>A<sub>1</sub></b> | 0.38        | 1.27  | 0.015  | 0.050 |
| <b>B</b>             | 0.38        | 0.51  | 0.015  | 0.020 |
| <b>B<sub>1</sub></b> | 0.89        | 1.65  | 0.035  | 0.065 |
| <b>C</b>             | 0.20        | 0.30  | 0.008  | 0.012 |
| <b>D</b>             | 9.02        | 10.92 | 0.355  | 0.430 |
| <b>E</b>             | 7.62        | 8.26  | 0.300  | 0.325 |
| <b>E<sub>1</sub></b> | 5.59        | 7.11  | 0.220  | 0.280 |
| <b>e<sub>1</sub></b> | 2.29        | 2.79  | 0.090  | 0.110 |
| <b>e<sub>A</sub></b> | 7.37        | 7.87  | 0.290  | 0.310 |
| <b>L</b>             | 2.79        | 3.81  | 0.110  | 0.150 |
| <b>Q<sub>1</sub></b> | 1.27        | 2.03  | 0.050  | 0.080 |
| <b>S</b>             | 0.76        | 1.65  | 0.030  | 0.065 |

ECN: S-03946—Rev. E, 09-Jul-01  
DWG: 5478

NOTE: End leads may be half leads.



**CERDIP: 8-LEAD**



| Dim                                         | MILLIMETERS |       | INCHES    |       |
|---------------------------------------------|-------------|-------|-----------|-------|
|                                             | Min         | Max   | Min       | Max   |
| A                                           | 4.06        | 5.08  | 0.160     | 0.200 |
| A <sub>1</sub>                              | 0.51        | 1.14  | 0.020     | 0.045 |
| B                                           | 0.38        | 0.51  | 0.015     | 0.020 |
| B <sub>1</sub>                              | 1.14        | 1.65  | 0.045     | 0.065 |
| C                                           | 0.20        | 0.30  | 0.008     | 0.012 |
| D                                           | 9.40        | 10.16 | 0.370     | 0.400 |
| E                                           | 7.62        | 8.26  | 0.300     | 0.325 |
| E <sub>1</sub>                              | 6.60        | 7.62  | 0.260     | 0.300 |
| e <sub>1</sub>                              | 2.54 BSC    |       | 0.100 BSC |       |
| e <sub>A</sub>                              | 7.62 BSC    |       | 0.300 BSC |       |
| L                                           | 3.18        | 3.81  | 0.125     | 0.150 |
| L <sub>1</sub>                              | 3.18        | 5.08  | 0.150     | 0.200 |
| Q <sub>1</sub>                              | 1.27        | 2.16  | 0.050     | 0.085 |
| S                                           | 0.64        | 1.52  | 0.025     | 0.060 |
| ∞                                           | 0°          | 15°   | 0°        | 15°   |
| ECN: S-03946—Rev. C, 09-Jul-01<br>DWG: 5348 |             |       |           |       |



## Mounting LITTLE FOOT®, SO-8 Power MOSFETs

Wharton McDaniel

Surface-mounted LITTLE FOOT power MOSFETs use integrated circuit and small-signal packages which have been modified to provide the heat transfer capabilities required by power devices. Leadframe materials and design, molding compounds, and die attach materials have been changed, while the footprint of the packages remains the same.

See Application Note 826, *Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs*, (<http://www.vishay.com/ppg?72286>), for the basis of the pad design for a LITTLE FOOT SO-8 power MOSFET. In converting this recommended minimum pad to the pad set for a power MOSFET, designers must make two connections: an electrical connection and a thermal connection, to draw heat away from the package.

In the case of the SO-8 package, the thermal connections are very simple. Pins 5, 6, 7, and 8 are the drain of the MOSFET for a single MOSFET package and are connected together. In a dual package, pins 5 and 6 are one drain, and pins 7 and 8 are the other drain. For a small-signal device or integrated circuit, typical connections would be made with traces that are 0.020 inches wide. Since the drain pins serve the additional function of providing the thermal connection to the package, this level of connection is inadequate. The total cross section of the copper may be adequate to carry the current required for the application, but it presents a large thermal impedance. Also, heat spreads in a circular fashion from the heat source. In this case the drain pins are the heat sources when looking at heat spread on the PC board.

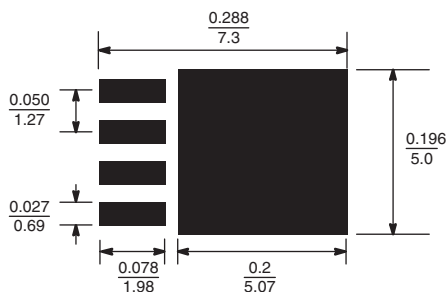


Figure 1. Single MOSFET SO-8 Pad Pattern With Copper Spreading

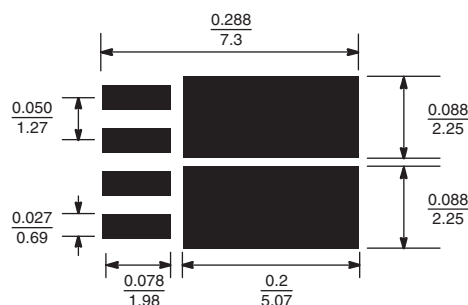


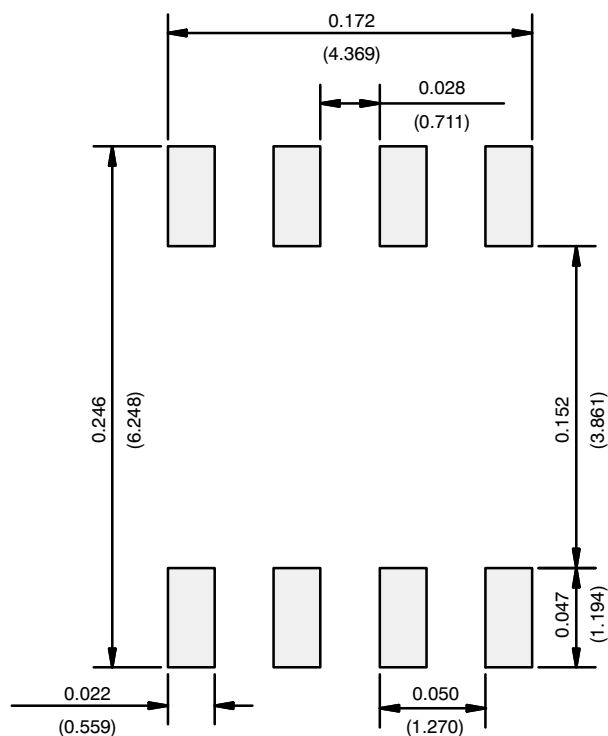
Figure 2. Dual MOSFET SO-8 Pad Pattern With Copper Spreading

The minimum recommended pad patterns for the single-MOSFET SO-8 with copper spreading (Figure 1) and dual-MOSFET SO-8 with copper spreading (Figure 2) show the starting point for utilizing the board area available for the heat-spreading copper. To create this pattern, a plane of copper overlies the drain pins. The copper plane connects the drain pins electrically, but more importantly provides planar copper to draw heat from the drain leads and start the process of spreading the heat so it can be dissipated into the ambient air. These patterns use all the available area underneath the body for this purpose.

Since surface-mounted packages are small, and reflow soldering is the most common way in which these are affixed to the PC board, “thermal” connections from the planar copper to the pads have not been used. Even if additional planar copper area is used, there should be no problems in the soldering process. The actual solder connections are defined by the solder mask openings. By combining the basic footprint with the copper plane on the drain pins, the solder mask generation occurs automatically.

A final item to keep in mind is the width of the power traces. The absolute minimum power trace width must be determined by the amount of current it has to carry. For thermal reasons, this minimum width should be at least 0.020 inches. The use of wide traces connected to the drain plane provides a low impedance path for heat to move away from the device.

## RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads  
Dimensions in Inches/(mm)

[Return to Index](#)



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